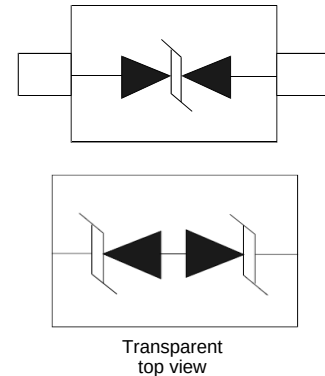


## Features

- Bidirectional ESD protection of one line
- Very low diode capacitance:  $C_d = 11 \text{ pF}$
- Max. peak pulse power:  $P_{PP} = 45 \text{ W}$
- Low clamping voltage:  $V_{CL} = 12.5 \text{ V}$
- Ultra low leakage current:  $I_{RM} < 1 \text{ nA}$
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge);  $I_{PP} = 4.8 \text{ A}$
- AEC-Q101 qualified



## Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber Identity Module (SIM) card protection
- Communication systems
- Portable electronics
- 10/100 Mbit/s Ethernet
- FireWire

## Mechanical Data

- SOD-882 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

## Quick reference data

### Quick reference data

$T_{amb} = 25 \text{ °C}$  unless otherwise specified.

| Symbol    | Parameter                | Conditions                             | Min | Typ | Max | Unit |
|-----------|--------------------------|----------------------------------------|-----|-----|-----|------|
| $V_{RWM}$ | reverse standoff voltage |                                        | -   | -   | 5   | V    |
| $C_d$     | diode capacitance        | $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ | -   | 11  | 13  | pF   |

## Ordering information

Ordering information

| Type number | Package |                                                                            |         |
|-------------|---------|----------------------------------------------------------------------------|---------|
|             | Name    | Description                                                                | Version |
| PESD5V0V1BA | SC-76   | plastic surface-mounted package; 2 leads                                   | SOD323  |
| PESD5V0V1BB | SC-79   | plastic surface-mounted package; 2 leads                                   | SOD523  |
| PESD5V0V1BL | -       | leadless ultra small plastic package; 2 terminals; body 1.0 ? 0.6 ? 0.5 mm | SOD882  |

## Limiting values

Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol          | Parameter          | Conditions               |     | Min | Max | Unit |
|-----------------|--------------------|--------------------------|-----|-----|-----|------|
| Per diode       |                    |                          |     |     |     |      |
| P <sub>PP</sub> | peak pulse power   | t <sub>p</sub> = 8/20 ?s | [1] | -   | 45  | W    |
| I <sub>PP</sub> | peak pulse current | t <sub>p</sub> = 8/20 ?s | [1] | -   | 4.8 | A    |

Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| Per device       |                      |            |     |      |      |
| T <sub>j</sub>   | junction temperature |            | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature  |            | -55 | +150 | °C   |
| T <sub>stg</sub> | storage temperature  |            | -65 | +150 | °C   |

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

### ESD maximum ratings

T<sub>amb</sub> = 25 °C unless otherwise specified.

| Symbol           | Parameter                       | Conditions                        |     | Min | Max | Unit |
|------------------|---------------------------------|-----------------------------------|-----|-----|-----|------|
| V <sub>ESD</sub> | electrostatic discharge voltage | IEC 61000-4-2 (contact discharge) | [1] | -   | 30  | kV   |
|                  |                                 | machine model                     |     | -   | 2   | kV   |
|                  |                                 | MIL-STD-883 (human body model)    |     | -   | 16  | kV   |

[1] Device stressed with ten non-repetitive ESD pulses.

### ESD standards compliance

| Standard                                 | Conditions                      |
|------------------------------------------|---------------------------------|
| IEC 61000-4-2; level 4 (ESD)             | > 15 kV (air); > 8 kV (contact) |
| MIL-STD-883; class 3B (human body model) | > 8 kV                          |

## Characteristics

### Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

| Symbol             | Parameter                | Conditions              |     | Min | Typ | Max  | Unit     |
|--------------------|--------------------------|-------------------------|-----|-----|-----|------|----------|
| $V_{RWM}$          | reverse standoff voltage |                         |     | -   | -   | 5    | V        |
| $I_{RM}$           | reverse leakage current  | $V_{RWM} = 5\text{ V}$  |     | -   | < 1 | 10   | nA       |
| $V_{BR}$           | breakdown voltage        | $I_R = 5\text{ mA}$     |     | 5.8 | 6.8 | 7.8  | V        |
| $C_d$              | diode capacitance        | $f = 1\text{ MHz};$     |     | -   | 11  | 13   | pF       |
| $V_R = 0\text{ V}$ |                          |                         |     |     |     |      |          |
| $V_{CL}$           | clamping voltage         | $I_{PP} = 4.8\text{ A}$ | [1] | -   | -   | 12.5 | V        |
| $r_{dyn}$          | dynamic resistance       | $I_R = 10\text{ A}$     | [2] | -   | 0.2 | -    | $\Omega$ |
| $r_{dif}$          | differential resistance  | $I_R = 5\text{ mA}$     |     | -   | -   | 35   | $\Omega$ |

[1] Non-repetitive current pulse 8/20  $\mu\text{s}$  exponential decay waveform according to IEC 61000-4-5.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP)  $t_p = 100\text{ ns}$ ; square pulse;  
ANS/IESD STM5.1-2008.

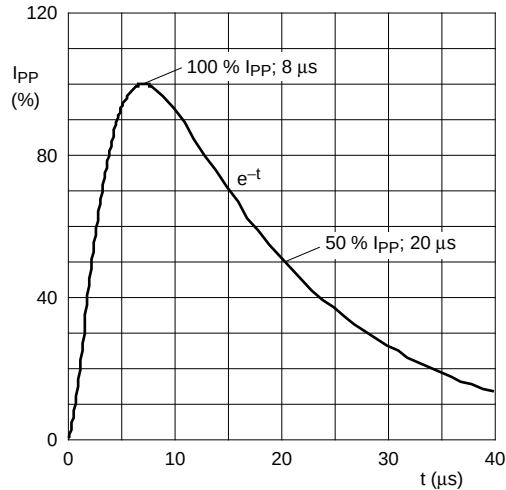


Fig 1. 8/20  $\mu\text{s}$  pulse waveform according to IEC 61000-4-5

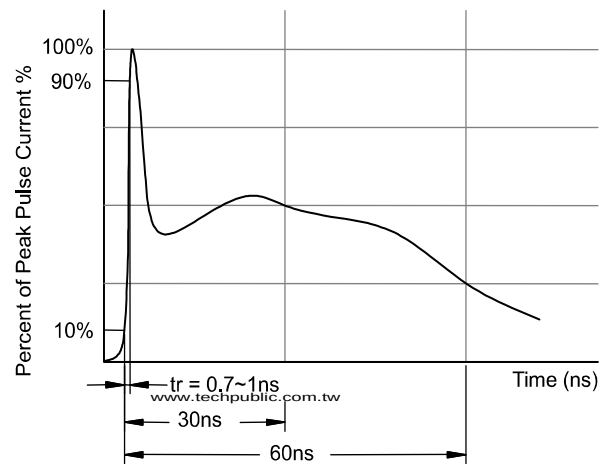


Fig 2. ESD pulse waveform according to IEC 61000-4-2

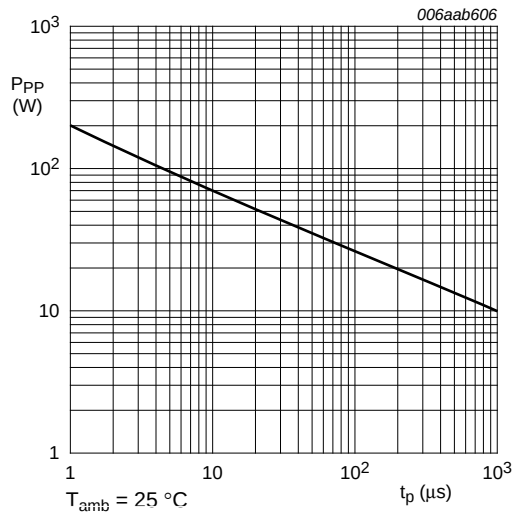


Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

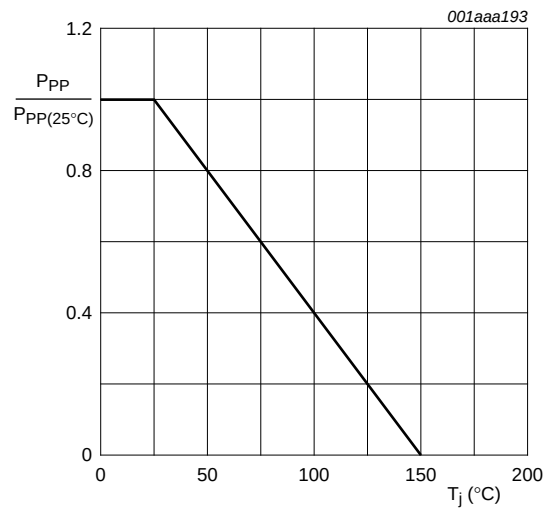


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values

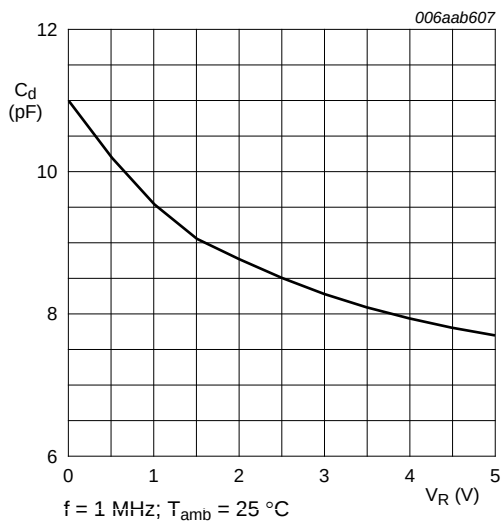


Fig 5. Diode capacitance as a function of reverse voltage; typical values

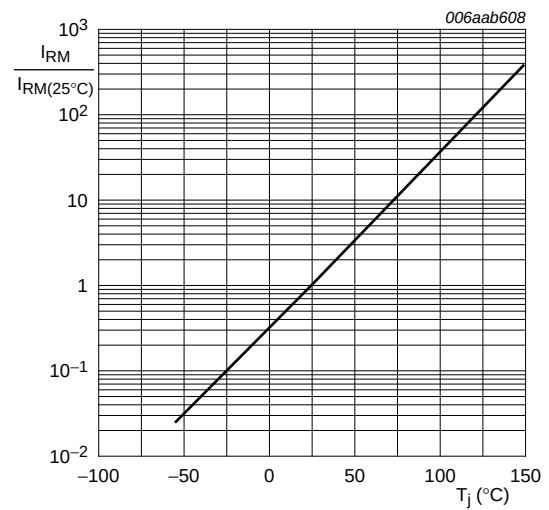
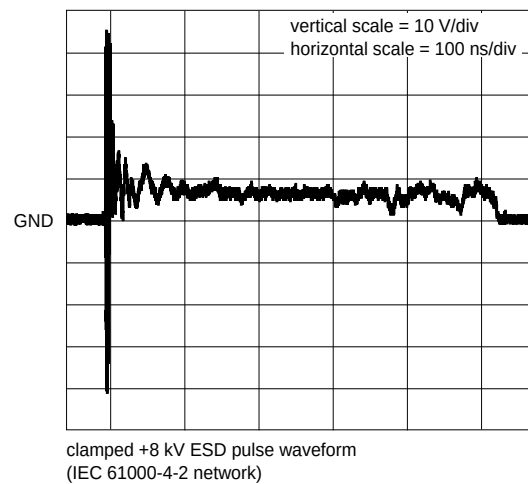
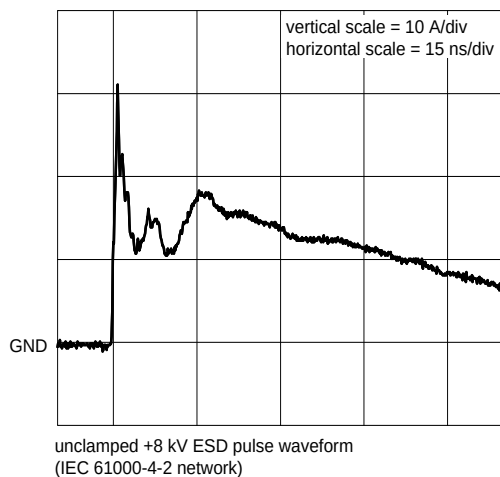
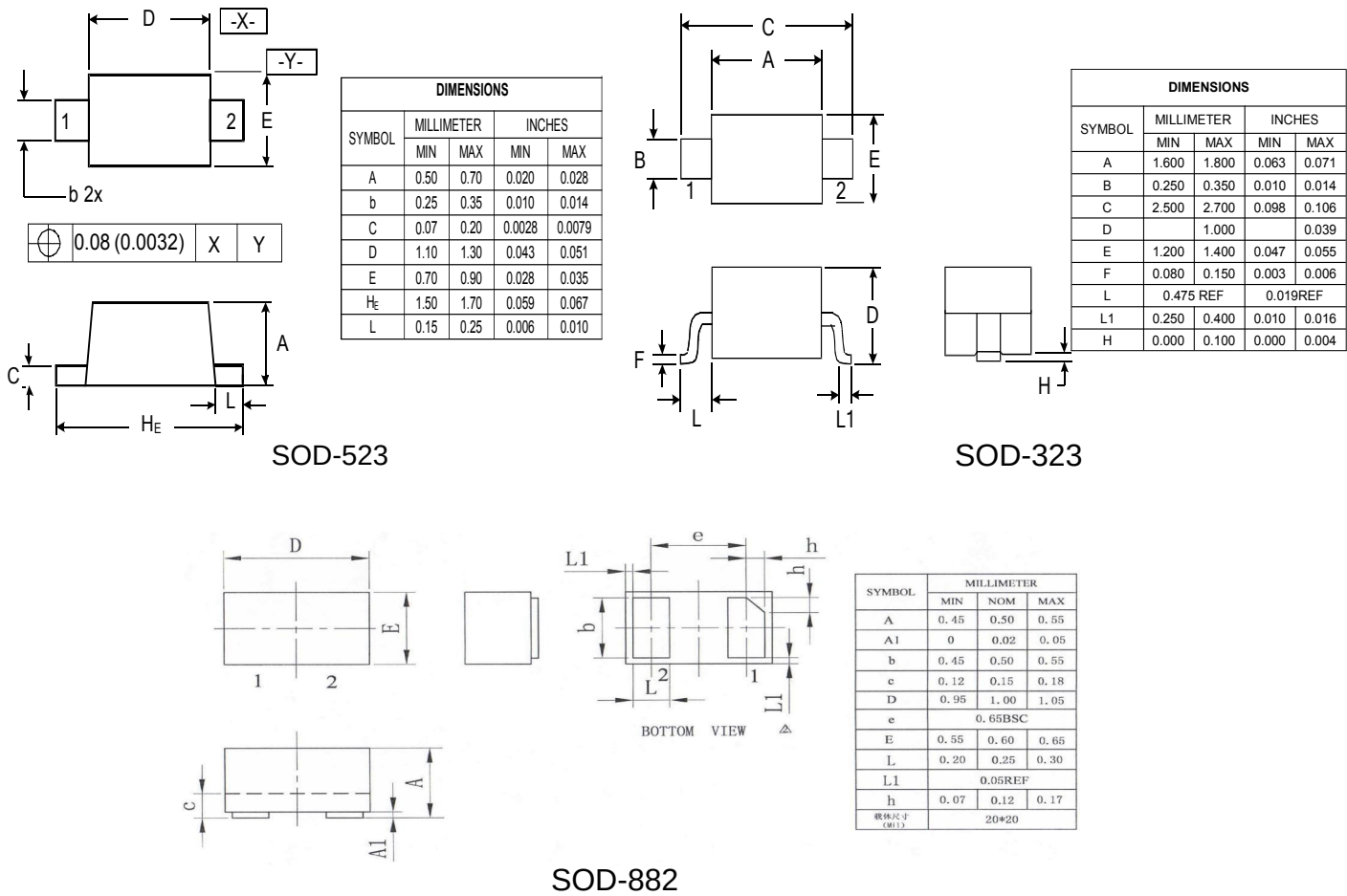


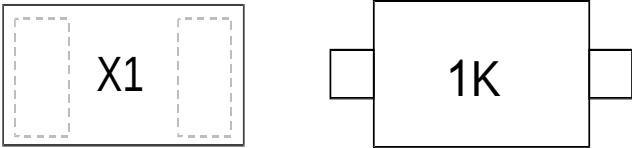
Fig 6. Relative variation of reverse leakage current as a function of junction temperature; typical values



Outline Drawing – SOD-323/SOD-523/SOD-882



Marking



Ordering information

| Order code  | Marking codes | Package | Baseqty | Deliverymode  |
|-------------|---------------|---------|---------|---------------|
| PESD5V0V1BA | 1K            | SOD-323 | 10000   | Tape and reel |
| PESD5V0V1BB | Z9            | SOD-523 | 10000   | Tape and reel |
| PESD5V0V1BL | X1            | SOD-882 | 10000   | Tape and reel |